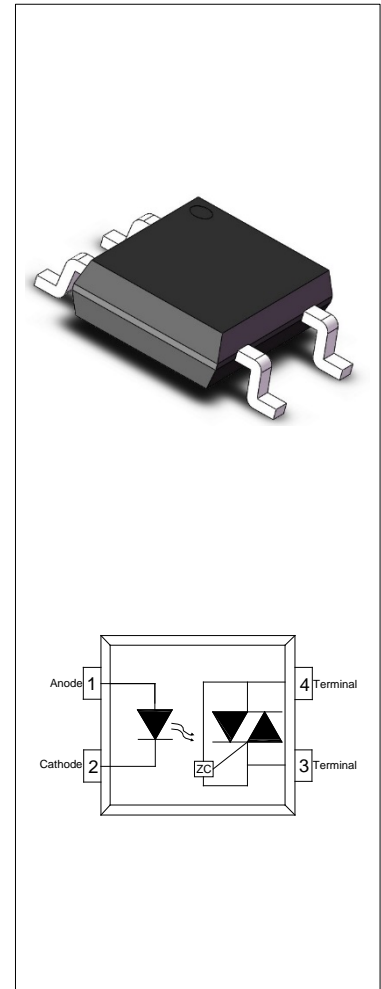


## JOC303XM4 Series

Rev.A.1.0

### DESCRIPTION:

The JOC303XM4 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon zero-crossing photo triac in a plastic SOP4 package. With the robust coplanar double mold structure, JOC303XM4 series provide the most stable isolation feature. The products are widely used in solenoid/value controls, lighting controls, motor controls, temperature controls, static AC power switches, solid state relays, interfacing microprocessors up to 120 V<sub>AC</sub> peripherals.



### MAIN FEATURES

- High isolation 3750 VRMS
- DC input with zero-crossing photo triac output
- Operating temperature range -55 °C to 100 °C
- REACH compliance
- Halogen free
- MSL class 1
- HBM: H3A ; MM: M4
- CQC approved
- VDE approved
- UL approved

### ABSOLUTE MAXIMUM RATINGS (Temperature=25°C)

Parameter		Symbol	Value	Unit
Input	Forward Current	I <sub>F</sub>	60	mA
	Reverse Voltage	V <sub>R</sub>	6	V
	Junction Temperature	T <sub>j</sub>	125	°C
	Input Power Dissipation	P <sub>I</sub>	100	mW
	Power Dissipation Derating (T <sub>a</sub> ≥ 25°C)	Δ P <sub>D</sub> /°C	-1.33	mW/°C
Output	Off-state Output Terminal Voltage	V <sub>OFF</sub>	250	V
	Peak On-state Current (100μs pulse, 120 pps)	I <sub>TP</sub>	2	A
	On-state RMS Current	I <sub>T(RMS)</sub>	100	mA

	Peak Repetitive Surge Current ( $P_W=10$ ms)	$I_{TSM}$	1	A
	Junction Temperature	$T_j$	125	$^{\circ}C$
	Output Power Dissipation	$P_O$	250	mW
	Power Dissipation Derating ( $T_a \geq 25^{\circ}C$ )	$\Delta P_D/^{\circ}C$	-3.33	mW/ $^{\circ}C$
Total Power Dissipation		$P_{tot}$	350	mW
Isolation Voltage		$V_{iso}$	3750 <sup>①</sup>	$V_{rms}$
Operating Temperature		$T_{opr}$	-55~100	$^{\circ}C$
Storage Temperature		$T_{stg}$	-55~150	$^{\circ}C$
Soldering Temperature		$T_{sol}$	260 <sup>②</sup>	$^{\circ}C$

**NOTE1**: AC for 1minute, R.H.=40~60%

**NOTE2**: For 10 seconds

**ELECTRICAL CHARACTERISTICS** (Temperature=25 $^{\circ}C$ )

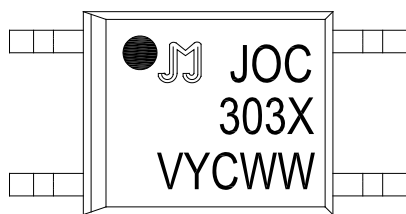
Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit	
Input	Forward Voltage	$V_F$	$I_F=10mA$	-	1.2	1.4	V	
	Reverse Current	$I_R$	$V_R=6V$	-	-	1	$\mu A$	
	Input Capacitance	$C_{in}$	$V=0, f=1kHz$	-	10	-	pF	
Output	Peak Off-state Current, Either Direction	$I_{OFF}$	$V_{OFF}=250V, I_F=0$	-	-	100 <sup>③</sup>	nA	
	Peak On-state Voltage, Either Direction	$V_{TM}$	$I_{TM}=100mA$	-	1.7	2.5	V	
	Critical Rate of Rise of Off-state voltage	$dV/dt$	$V_{PEAK}=250V, I_F=0$	1000 <sup>④</sup>	-	-	V/ $\mu s$	
Transfer Characteristics	LED Trigger Current	JOC3031M4	Terminal Voltage=3V $I_{TM}=100mA$	-	-	15	mA	
		JOC3032M4		-	-	10		
		JOC3033M4		-	-	5		
	Holding Current		$I_H$	$I_{TM}=2mA, I_F=Rated I_{FT}$	-	250	-	$\mu A$
	Isolation Resistance		$R_{ISO}$	DC500V 40~60%R.H.	$10^{12}$	$10^{14}$	-	$\Omega$
	Floating Capacitance		$C_{IO}$	$V=0, f=1MHz$	-	8	-	pF
	Response Time		$t_{on}$	$V_D=6V, R_L=100\Omega, I_F=20mA$	-	15	50	$\mu s$

Zero-Crossing Characteristics	Inhibit Voltage	$V_{IH}$	$I_F=Rated$ $I_{FT}$	-	-	20	V
	Leakage in Inhibited State	$I_{OFF2}$	$I_F=Rated$ $I_{FT}$ $V_{OFF}=Rated$ $V_{OFF}$	-	-	5	mA

**NOTE3** : Test voltage must be applied within dV/dt ratings.

**NOTE4** : Refer to Fig.14 & Fig.15

**ORDERING AND MARKING INFORMATION**

<b>MARKING INFORMATION</b>			
		<p>JOC : Company Abbr. 303X : Part Number &amp; Rank VYCWW : LOT NO.</p>	
<b>ORDERING INFORMATION</b>			
<b>JOC303MX(Z)-GV</b>			
<p>JOC – Company Abbr. 303X – Rank (1/2/3) MX– SOP Package Z – Tape and Reel Option (T1/T2) G – Green V – VDE Option (V or None)</p>			
<b>Packing Quantity</b>			
<b>Option</b>	<b>Quantity</b>	<b>Quantity – Inner box</b>	<b>Quantity –Outer box</b>
T1/T2	3000 Units/Reel	4 Reels/Inner box	5 Inner box/Outer box =60k Units

Characteristics Curves

FIG.1: Forward Current vs. Ambient Temperature

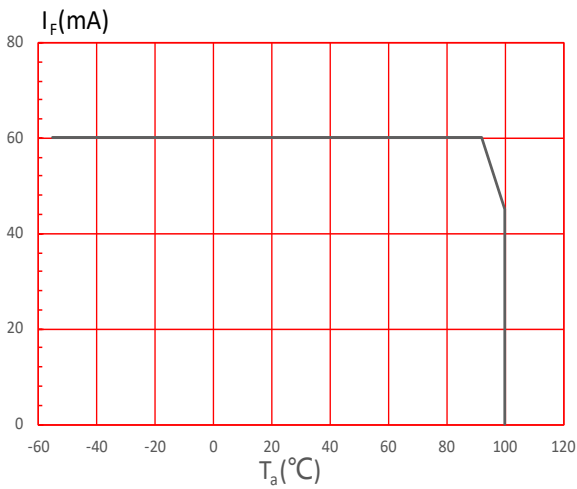


FIG.2: On-state Terminal Current vs. Ambient Temperature

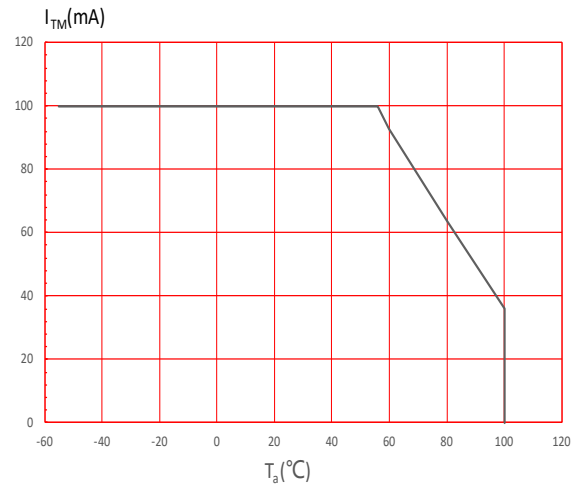


FIG.3: Forward Current vs. Forward Voltage

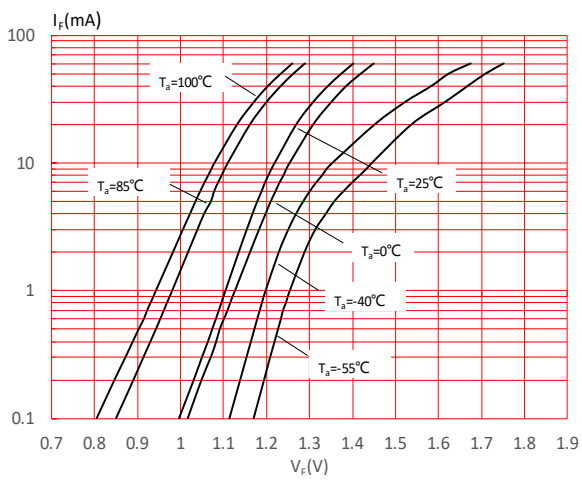


FIG.4: Normalized Off-state Terminal Current vs. Ambient Temperature

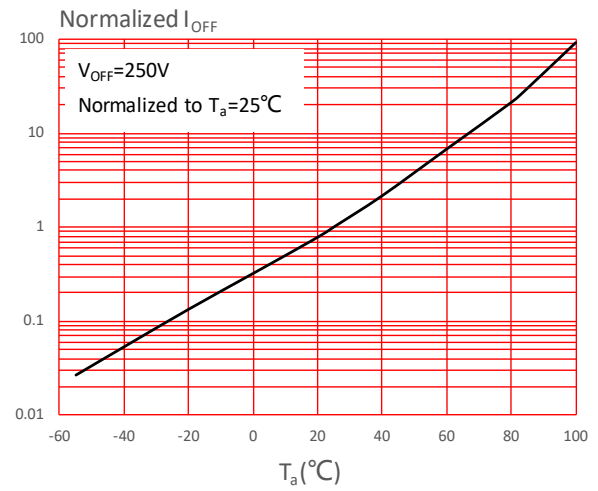


FIG.5: Normalized Off-state Terminal Voltage vs. Ambient Temperature

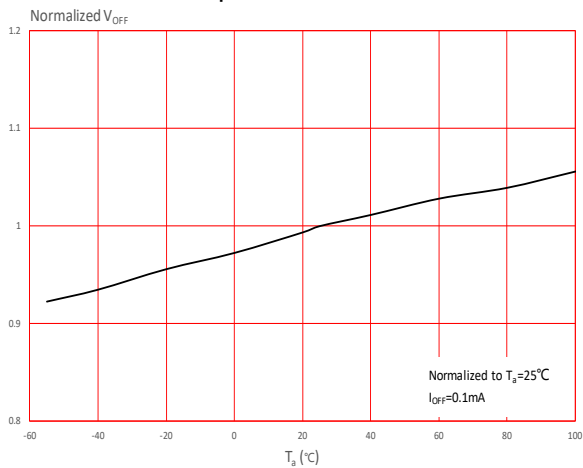
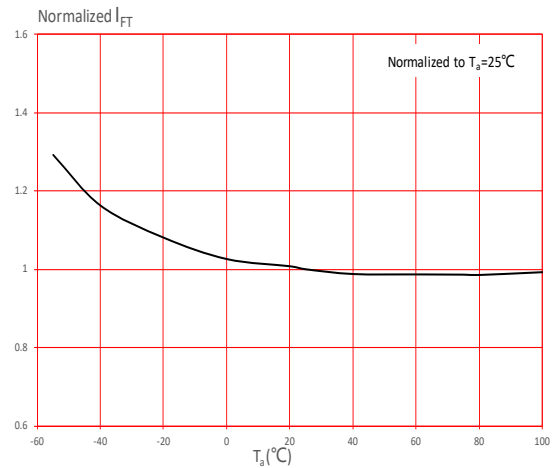
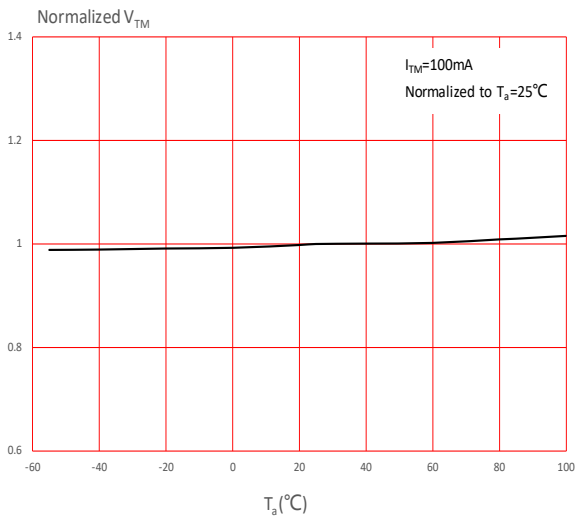


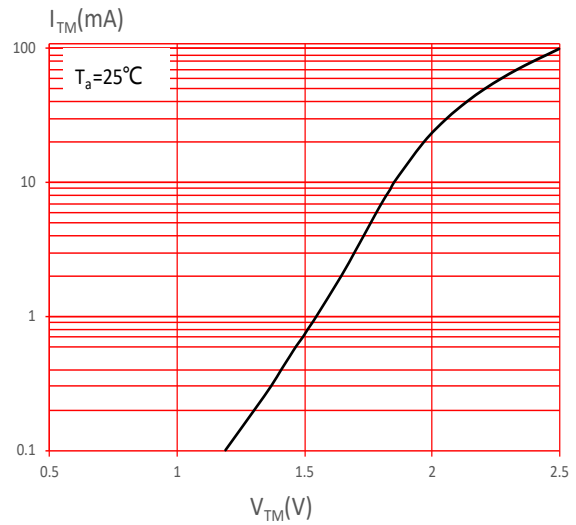
FIG.6: Normalized Trigger Current vs. Ambient Temperature



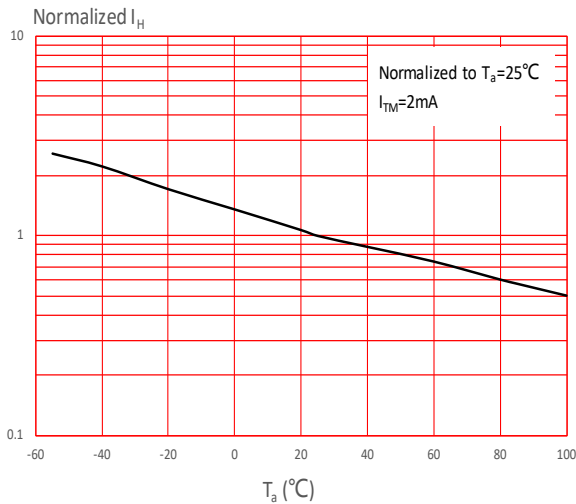
**FIG.7:** Normalized On-state Terminal Voltage vs. Ambient Temperature



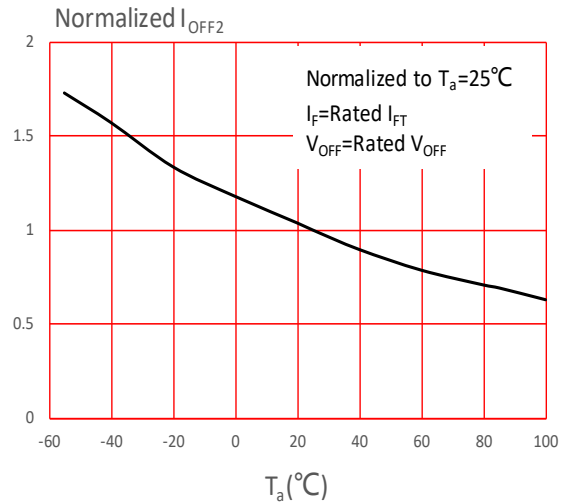
**FIG.8:** On-state Terminal Voltage vs. On-state Terminal Current



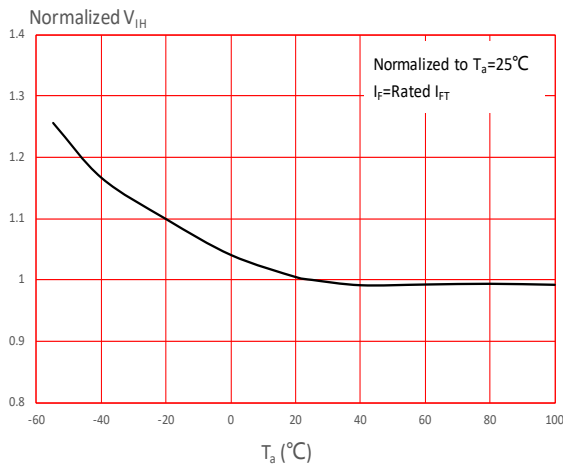
**FIG.9:** Normalized Holding Current vs. Ambient Temperature



**FIG.10:** Normalized Leakage in Inhibit State vs. Ambient Temperature



**FIG.11:** Normalized Inhibit Voltage vs. Ambient Temperature



TEST CIRCUITS

FIG.12: Test Circuits of Turn On Time



FIG.13: Waveforms of Turn On Time

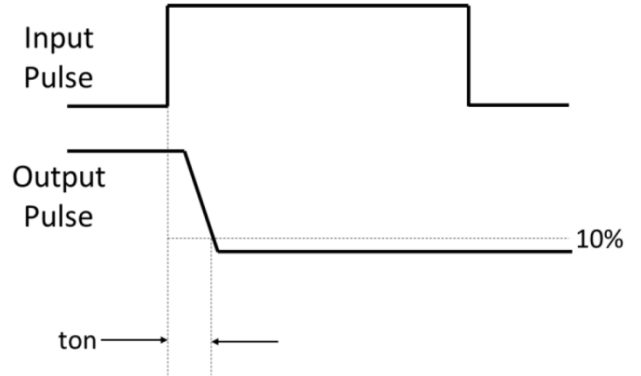


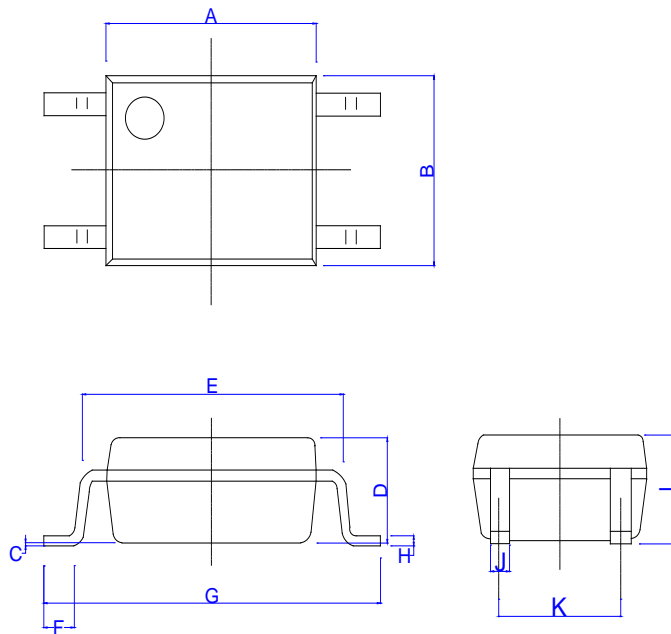
Fig.14: Test Circuits of dV/dt



Fig.15: Waveforms of dV/dt

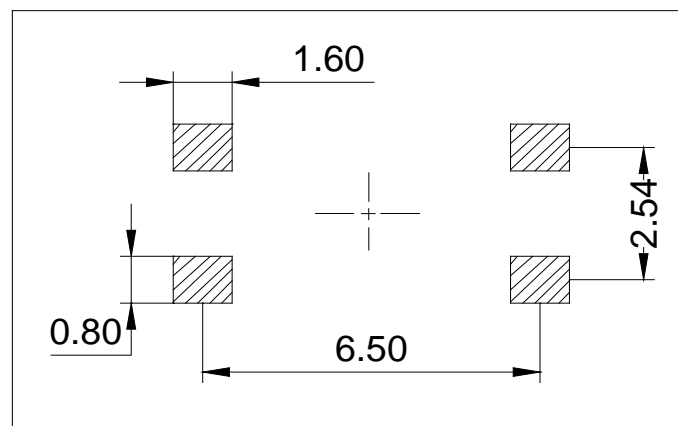


Package Dimension (Unit: mm)



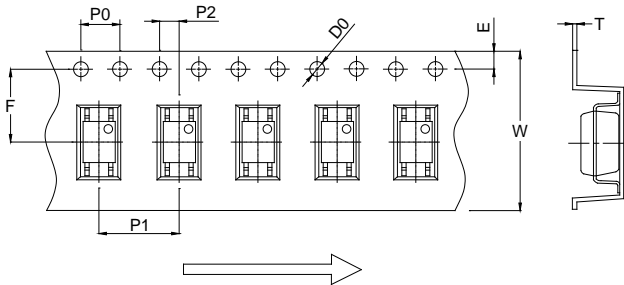
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.20		4.85	0.165		0.191
B	3.30		4.40	0.130		0.173
C	0.00		0.20	0.000		0.008
D	1.75		2.80	0.069		0.110
E	4.90		5.80	0.193		0.228
F	0.30		0.90	0.012		0.035
G	6.30		7.30	0.248		0.287
H	0.10		0.30	0.004		0.012
I	1.80		2.90	0.071		0.114
J	0.25		0.55	0.010		0.022
K	2.29		2.79	0.090		0.110

RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)



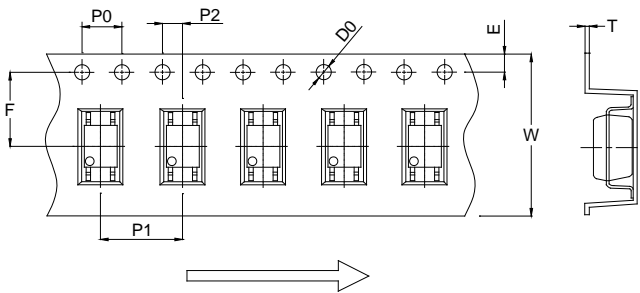
**CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**

**Option T1**



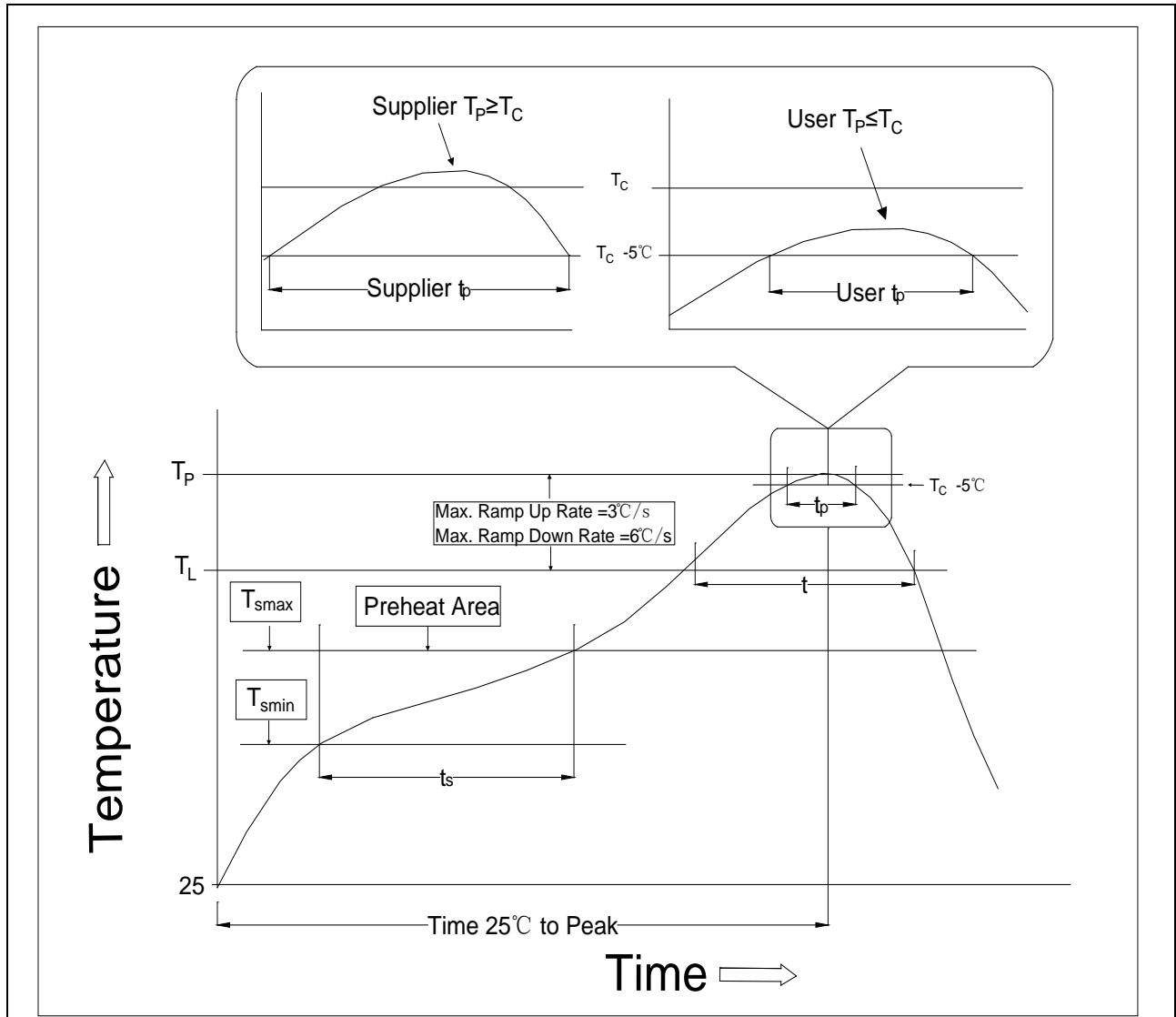
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.45	1.65		0.057	0.065
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.15	0.30	0.45	0.006	0.012	0.018
W	15.70	16.00	16.30	0.618	0.630	0.642

**Option T2**



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.45	1.65		0.057	0.065
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.15	0.30	0.45	0.006	0.012	0.018
W	15.70	16.00	16.30	0.618	0.630	0.642


REFLOW INFORMATION



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	100	150°C
Temperature Max. (T <sub>smax</sub> )	150	200°C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.	3°C/second max.
Liquidus Temperature (T <sub>L</sub> )	183°C	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C+0°C/-5°C	260°C+0°C/-5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

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